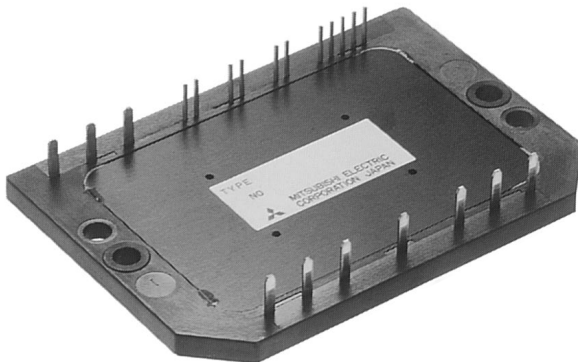


CM10MD-24H

MEDIUM POWER SWITCHING USE
INSULATED TYPE

CM10MD-24H



- IC 10A
- VCES 1200V
- Insulated Type
- CIB Module
- 3φ Inverter+3φ Converter+Brake
- UL Recognized

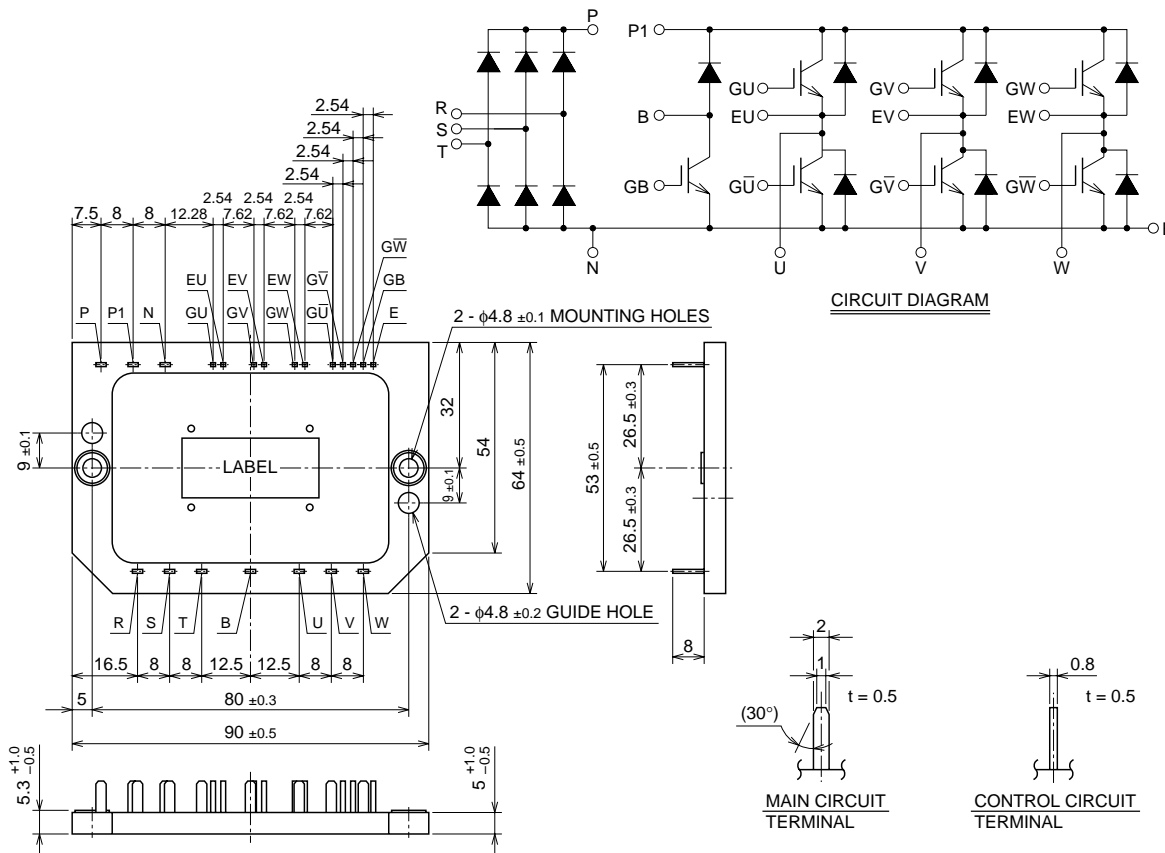
Yellow Card No. E80276 (N)
File No. E80271

APPLICATION

AC & DC motor controls, General purpose inverters, Servo controls, NC, Robotics

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



Note. Not use the guiding holes to mount on the cooling fin.

CM10MD-24H**MEDIUM POWER SWITCHING USE
INSULATED TYPE****MAXIMUM RATINGS** ($T_j = 25^\circ\text{C}$)**INVERTER PART**

Symbol	Parameter	Condition	Rating	Unit
V _{CES}	Collector-emitter voltage	G – E Short	1200	V
V _{GES}	Gate-emitter voltage	C – E Short	±20	V
I _C	Collector Current	T _C = 25°C	10	A
I _{CM}		PULSE (Note. 2)	20	A
I _E (Note. 1)	Emitter Current	T _C = 25°C	10	A
I _{EM} (Note. 1)		PULSE (Note. 2)	20	A
P _C (Note. 3)	Maximum collector dissipation	T _f = 25°C	57	W

BRAKE PART

Symbol	Parameter	Condition	Rating	Unit
V _{CES}	Collector-emitter voltage	G – E Short	1200	V
V _{GES}	Gate-emitter voltage	C – E Short	±20	V
I _C	Collector Current	T _C = 25°C	10	A
I _{CM}		PULSE (Note. 2)	20	A
P _C (Note. 3)	Maximum Collector dissipation	T _f = 25°C	57	W
V _{RRM}	Repetitive peak reverse voltage	Clamp diode part	1200	V
I _{FM} (Note. 3)	Forward current	Clamp diode part	10	A

CONVERTER PART

Symbol	Parameter	Condition	Rating	Unit
V _{RRM}	Repetitive peak reverse voltage		1600	V
E _a	Recommended AC input voltage		440	V
I _O	DC output current	3 ϕ rectifying circuit	10	A
I _{FSM}	Surge (non-repetitive) forward current	1 cycle at 60Hz, peak value Non-repetitive	100	A
I ² t	I ² t for fusing	Value for one cycle of surge current	42	A ² s

COMMON RATING

Symbol	Parameter	Condition	Rating	Unit
T _j	Junction temperature		-40 ~ +150	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
V _{iso}	Isolation voltage	AC 1 min.	2500	V
—	Mounting torque	Mounting M4 screw	1.47 ~ 1.96	N · m
—	Weight	Typical value	60	g

CM10MD-24H**MEDIUM POWER SWITCHING USE
INSULATED TYPE****ELECTRICAL CHARACTERISTICS** ($T_j = 25^\circ\text{C}$)**INVERTER PART**

Symbol	Parameter	Test conditions	Limits			Unit		
			Min.	Typ.	Max.			
ICES	Collector cutoff current	$V_{CE} = V_{CES}, V_{GE} = 0V$	—	—	1	mA		
$V_{GE(th)}$	Gate-emitter threshold voltage	$I_C = 1.0mA, V_{CE} = 10V$	4.5	6	7.5	V		
IGES	Gate-emitter cutoff current	$V_{GE} = V_{GES}, V_{CE} = 0V$	—	—	0.5	μA		
$V_{CE(sat)}$	Collector-emitter saturation voltage	$T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$I_C = 10A, V_{GE} = 15V$	(Note. 4)	—	2.7	3.4	V
					—	2.45	—	
C_{ies}	Input capacitance	$V_{CE} = 10V$ $V_{GE} = 0V$	—	—	2.0	nF		
C_{oes}	Output capacitance		—	—	1.5	nF		
C_{res}	Reverse transfer capacitance		—	—	0.4	nF		
QG	Total gate charge	$V_{CC} = 600V, I_C = 10A, V_{GE} = 15V$	—	50	—	nC		
$t_d(on)$	Turn-on delay time	$V_{CC} = 600V, I_C = 10A$	—	—	100	ns		
t_r	Turn-on rise time	$V_{GE1} = V_{GE2} = 15V$	—	—	200	ns		
$t_d(off)$	Turn-off delay time	$R_G = 31\Omega$	—	—	150	ns		
t_f	Turn-off fall time	Resistive load	—	—	350	ns		
V_{EC} (Note. 1)	Emitter-collector voltage	$I_E = 10A, V_{GE} = 0V$	—	—	3.5	V		
t_{rr} (Note. 1)	Reverse recovery time	$I_E = 10A, V_{GE} = 0V$	—	—	250	ns		
Q_{rr} (Note. 1)	Reverse recovery charge	$di_e / dt = -20A / \mu s$	—	0.08	—	μC		
$R_{th(j-f)Q}$ (Note. 5)	Thermal resistance	IGBT part, Per 1/6 module	—	—	2.2	$^\circ\text{C/W}$		
$R_{th(j-f)R}$ (Note. 5)		FWDi part, Per 1/6 module	—	—	3.1	$^\circ\text{C/W}$		

BRAKE PART

Symbol	Parameter	Condition	Limits			Unit		
			Min.	Typ.	Max.			
ICES	Collector cutoff current	$V_{CE} = V_{CES}, V_{GE} = 0V$	—	—	1	mA		
$V_{GE(th)}$	Gate-emitter threshold voltage	$I_C = 1.0mA, V_{CE} = 10V$	4.5	6	7.5	V		
IGES	Gate-emitter cutoff current	$V_{GE} = V_{GES}, V_{CE} = 0V$	—	—	0.5	μA		
$V_{CE(sat)}$	Collector-to-emitter saturation voltage	$T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$I_C = 10A, V_{GE} = 15V$	(Note. 4)	—	2.7	3.4	V
					—	2.45	—	
C_{ies}	Input capacitance	$V_{CE} = 10V$ $V_{GE} = 0V$	—	—	2.0	nF		
C_{oes}	Output capacitance		—	—	1.5	nF		
C_{res}	Reverse transfer capacitance		—	—	0.4	nF		
QG	Total gate charge	$V_{CC} = 600V, I_C = 10A, V_{GE} = 15V$	—	50	—	nC		
V_{FM}	Forward voltage drop	$I_F = 10A, \text{Clamp diode part}$	—	—	1.7	V		
$R_{th(j-f)Q}$ (Note. 5)	Thermal resistance	IGBT part	—	—	2.2	$^\circ\text{C/W}$		
$R_{th(j-f)R}$ (Note. 5)		Clamp diode part	—	—	2.7	$^\circ\text{C/W}$		

CONVERTER PART

Symbol	Parameter	Condition	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive reverse current	$V_R = V_{RRM}, T_j = 150^\circ\text{C}$	—	—	8	mA
V_{FM}	Forward voltage drop	$I_F = 10A$	—	—	1.7	V
$R_{th(j-f)}$ (Note. 5)	Thermal resistance	Per 1/6 module	—	—	2.7	$^\circ\text{C/W}$

Note 1. $I_E, V_{EC}, t_{rr}, Q_{rr}$ & di_e/dt represent characteristics of the anti-parallel, emitter to collector free-wheel diode.

2. Pulse width and repetition rate should be such that the device junction temp. (T_j) does not exceed T_{jmax} rating.

3. Junction temperature (T_j) should not increase beyond 150°C .

4. Pulse width and repetition rate should be such as to cause negligible temperature rise.

5. Thermal resistance is specified under following conditions.

• The conductive grease applied, between module and fin.

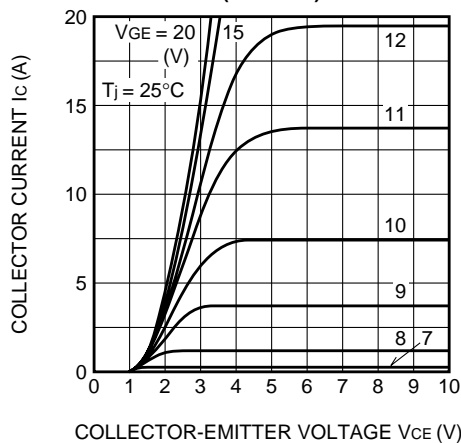
• Al plate is used as fin.

CM10MD-24H

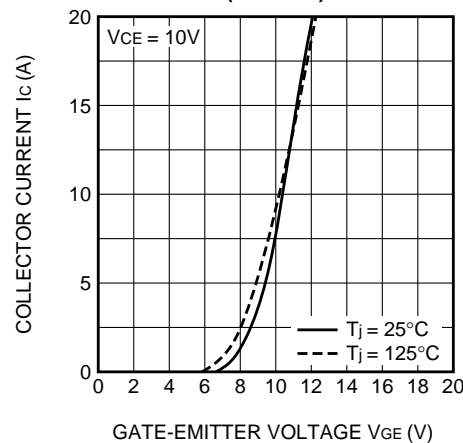
MEDIUM POWER SWITCHING USE
INSULATED TYPE

PERFORMANCE CURVES

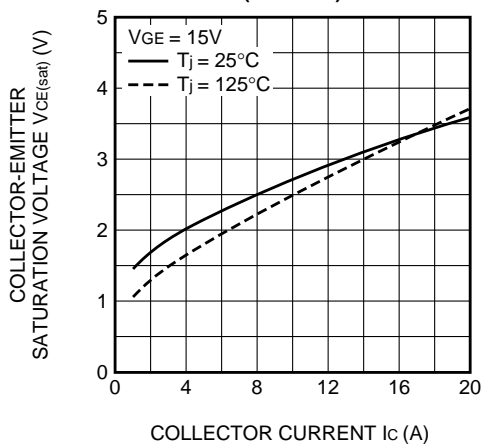
OUTPUT CHARACTERISTICS
(TYPICAL)



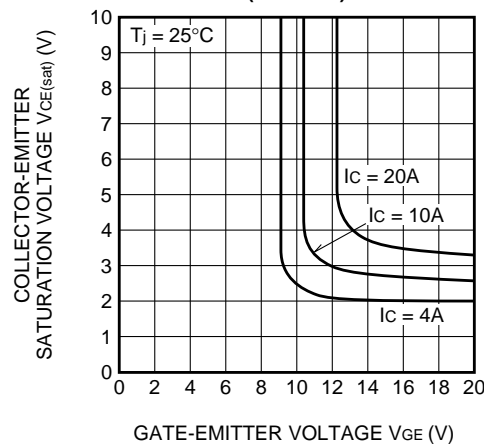
TRANSFER CHARACTERISTICS
(TYPICAL)



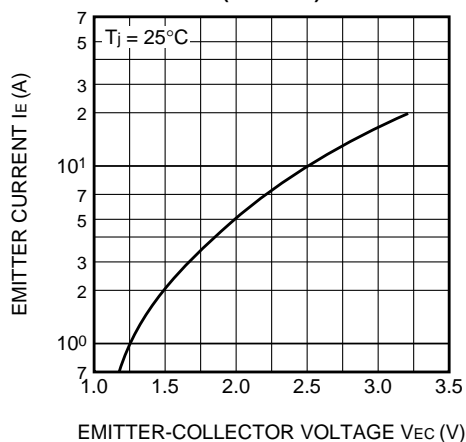
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



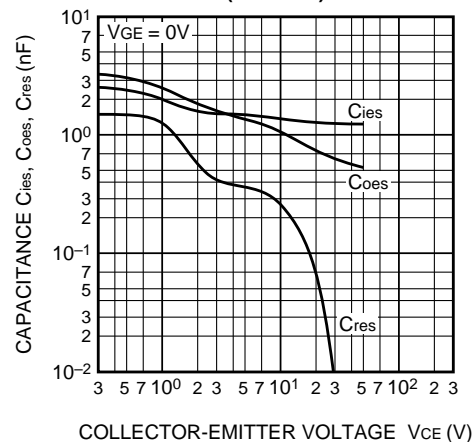
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



FREE-WHEEL DIODE
FORWARD CHARACTERISTICS
(TYPICAL)



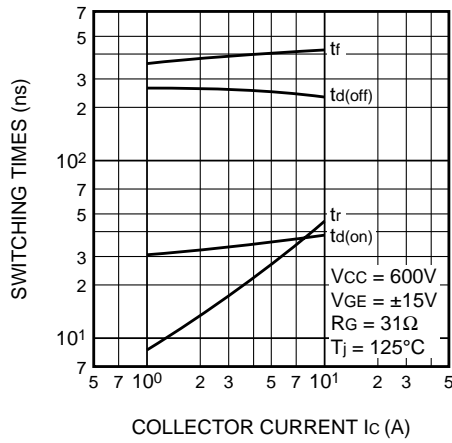
CAPACITANCE VS. V_{ce}
(TYPICAL)



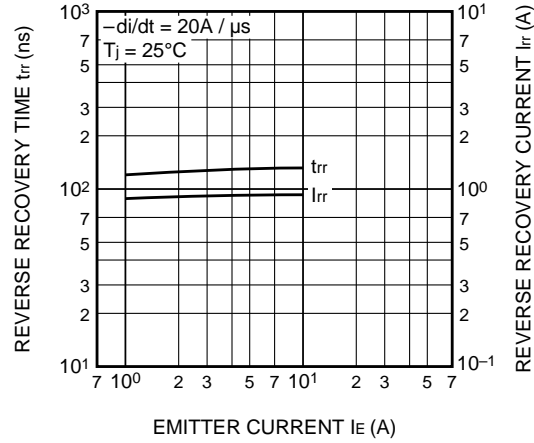
CM10MD-24H

MEDIUM POWER SWITCHING USE
INSULATED TYPE

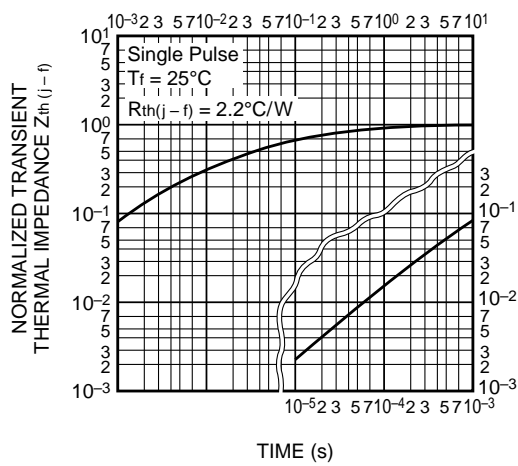
HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)



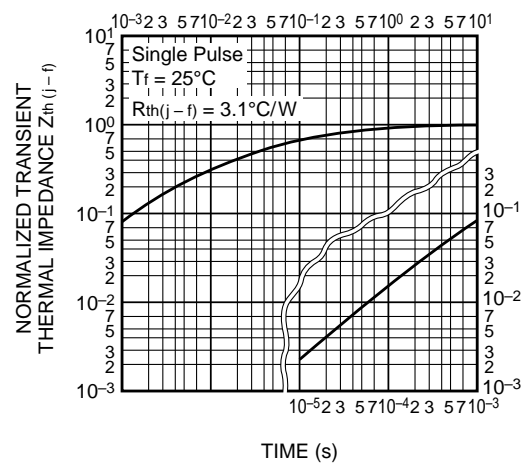
REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT part)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (FWDi part)



VGE - GATE CHARGE (TYPICAL)

